



PJQ5439E-AU

30V P-Channel Enhancement Mode MOSFET

Voltage **-30 V** **Current** **-33 A**

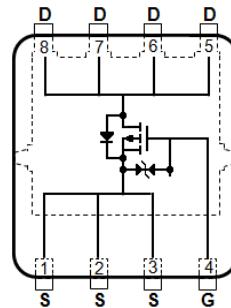
Features

- $R_{DS(ON)}$, $V_{GS} @ -10V$, $I_D @ -20A < 18.8m\Omega$
- $R_{DS(ON)}$, $V_{GS} @ -4.5V$, $I_D @ -10A < 30.7m\Omega$
- 100% UIS tested
- Reliable and Rugged
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN5060-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.08 grams

DFN5060-8L



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ C$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage	V_{DS}	-30	V
Gate-Source Voltage	V_{GS}	± 25	
Continuous Drain Current ^(Note 3)	I_D	-33	A
		-24	
Pulsed Drain Current ^(Note 1)	I_{DM}	-98	A
Power Dissipation	P_D	33	W
		17	
Continuous Drain Current ^(Note 4)	I_D	-10.5	A
		-8.8	
Power Dissipation	P_D	3.3	W
		2.3	
Single Pulse Avalanche Energy ^(Note 5)	E_{AS}	42	mJ
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55~175	°C
Thermal Resistance ^(Note 4)	Junction to Case	$R_{\theta JC}$	4.5
	Junction to Ambient	$R_{\theta JA}$	45
			°C/W



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Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	$\text{V}_{\text{GS}}=0\text{V}, \text{I}_D=-250\mu\text{A}$	-30	-	-	V
Gate Threshold Voltage	$\text{V}_{\text{GS(th)}}$	$\text{V}_{\text{DS}}=\text{V}_{\text{GS}}, \text{I}_D=-250\mu\text{A}$	-1	-1.8	-2.5	
Drain-Source On-State Resistance	$\text{R}_{\text{DS(on)}}$	$\text{V}_{\text{GS}}=-10\text{V}, \text{I}_D=-20\text{A}$	-	15	18.8	$\text{m}\Omega$
		$\text{V}_{\text{GS}}=-4.5\text{V}, \text{I}_D=-10\text{A}$	-	23.6	30.7	
Zero Gate Voltage Drain Current	I_{DSS}	$\text{V}_{\text{DS}}=-30\text{V}, \text{V}_{\text{GS}}=0\text{V}$	-	-	-1	μA
Gate-Source Leakage Current	I_{GSS}	$\text{V}_{\text{GS}}=\pm 25\text{V}, \text{V}_{\text{DS}}=0\text{V}$	-	-	± 10	μA
		$\text{V}_{\text{GS}}=\pm 10\text{V}, \text{V}_{\text{DS}}=0\text{V}$	-	-	± 1	
Dynamic ^(Note 6)						
Total Gate Charge	Q_g	$\text{V}_{\text{DS}}=-24\text{V}, \text{I}_D=-20\text{A}, \text{V}_{\text{GS}}=-10\text{V}$	-	22	-	nC
Gate-Source Charge	Q_{gs}		-	3	-	
Gate-Drain Charge	Q_{gd}		-	7	-	
Input Capacitance	C_{iss}	$\text{V}_{\text{DS}}=-25\text{V}, \text{V}_{\text{GS}}=0\text{V}, \text{f}=1\text{MHz}$	-	1012	-	pF
Output Capacitance	C_{oss}		-	145	-	
Reverse Transfer Capacitance	Crss		-	121	-	
Gate resistance	R_g	$\text{f}=1\text{MHz}$	-	10.4	-	Ω
Turn-On Delay Time	$\text{td}_{(\text{on})}$	$\text{V}_{\text{DS}}=-24\text{V}, \text{I}_D=-20\text{A}, \text{V}_{\text{GS}}=-10\text{V}, \text{R}_g=3\Omega$ <small>(Note 2)</small>	-	7	-	ns
Turn-On Rise Time	tr		-	3	-	
Turn-Off Delay Time	$\text{td}_{(\text{off})}$		-	36	-	
Turn-Off Fall Time	tf		-	40	-	
Drain-Source Diode						
Diode Forward Current	I_s	$\text{T}_c=25^\circ\text{C}$	-	-	-33	A
Pulsed Diode Forward Current	I_{SM}		-	-	-98	
Diode Forward Voltage	V_{SD}	$\text{I}_s=-20\text{A}, \text{V}_{\text{GS}}=0\text{V}$	-	-0.9	-1.3	V
Reverse Recovery Time	Tr_{r}	$\text{V}_{\text{GS}}=0\text{V}, \text{I}_s=-20\text{A}$ $d\text{I}_s/dt=100\text{A}/\text{us}$	-	16	-	ns
Reverse Recovery Charge	Q_{rr}		-	8	-	

NOTES :

1. Pulse width $\leq 300\text{us}$, Duty cycle $\leq 2\%$.
2. Essentially independent of operating temperature typical characteristics.
3. The maximum current rating is package limited.
4. R_{thJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
5. The test condition is $L=0.5\text{mH}$, $\text{I}_{\text{AS}}=-13\text{A}$, $\text{V}_{\text{DD}}=-30\text{V}$, $\text{V}_{\text{GS}}=-10\text{V}$, Starting $\text{T}_J=25^\circ\text{C}$.
6. Guaranteed by design, not subject to production testing.



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TYPICAL CHARACTERISTIC CURVES

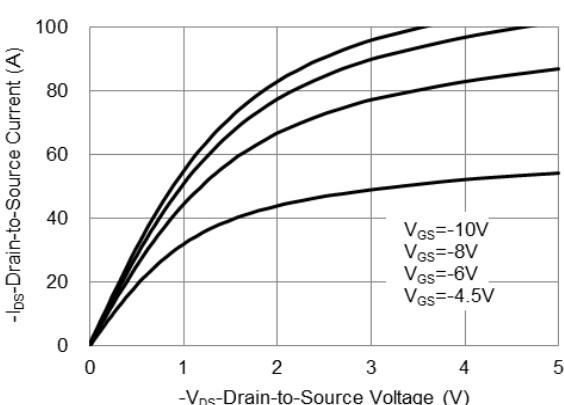


Fig.1 On-Region Characteristics

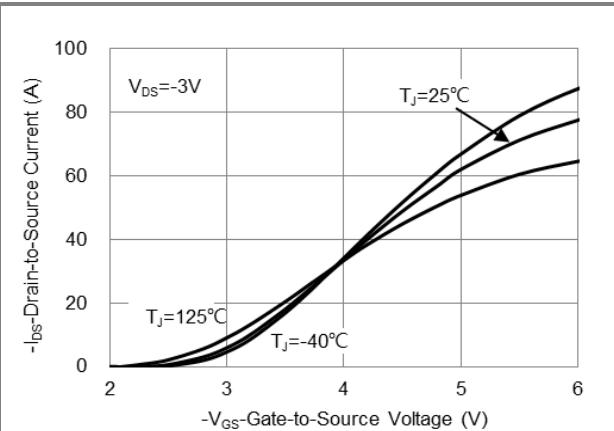


Fig.2 Transfer Characteristics

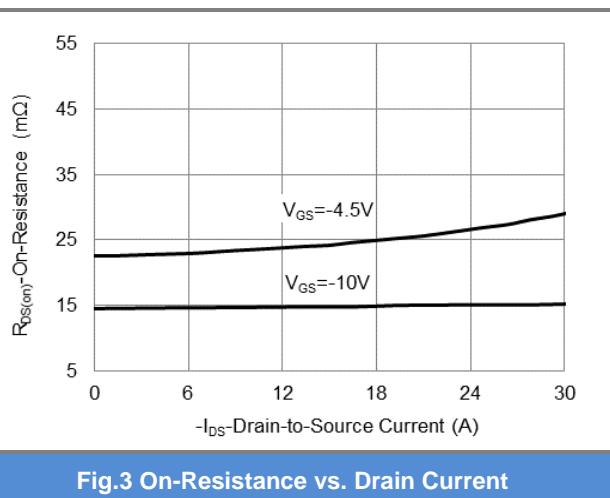


Fig.3 On-Resistance vs. Drain Current

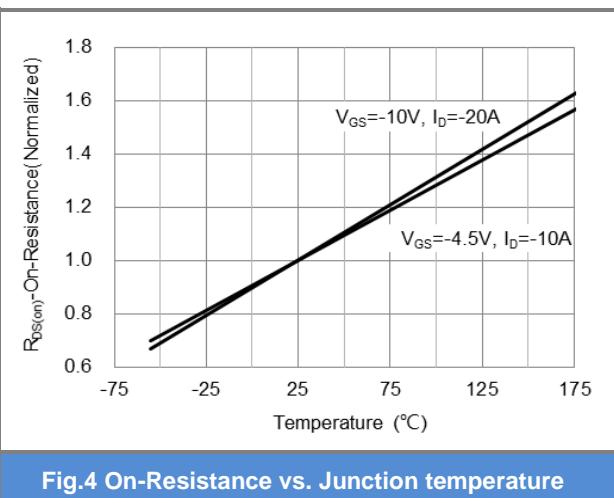


Fig.4 On-Resistance vs. Junction temperature

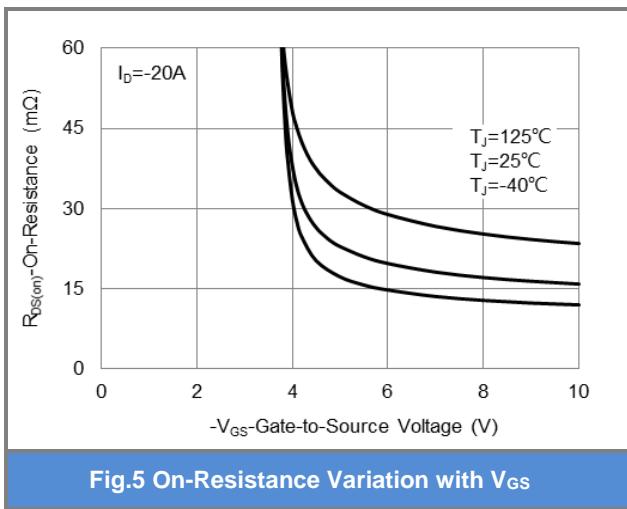


Fig.5 On-Resistance Variation with VGS

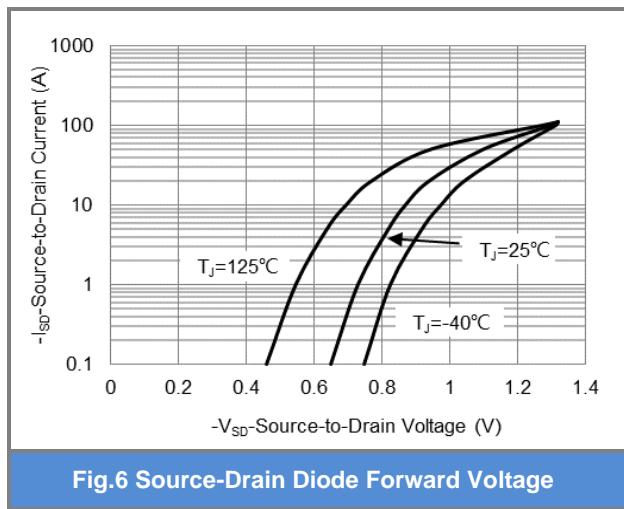


Fig.6 Source-Drain Diode Forward Voltage



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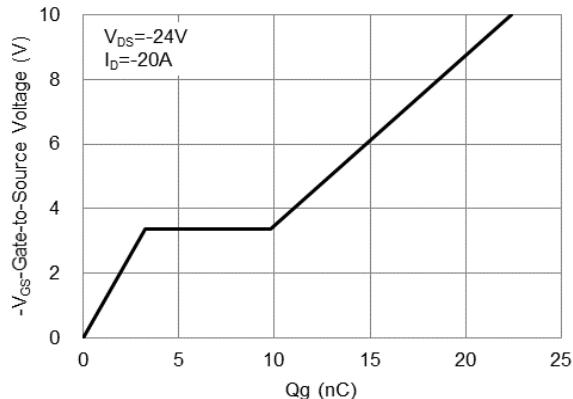


Fig.7 Gate-Charge Characteristics

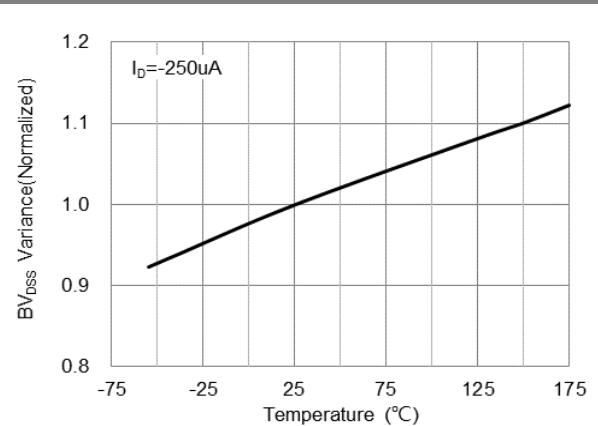


Fig.8 Breakdown Voltage Variation vs. Temperature

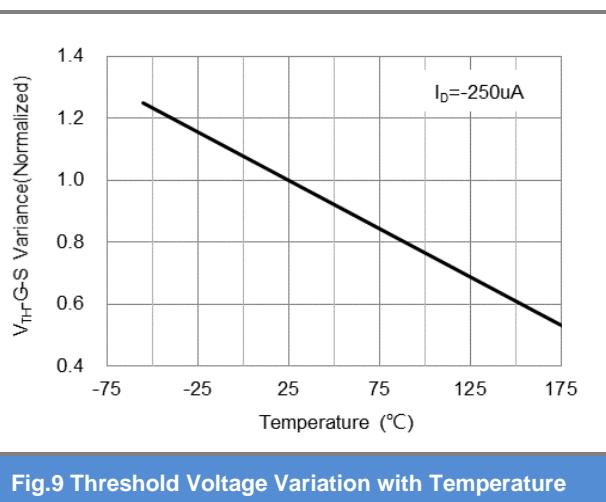


Fig.9 Threshold Voltage Variation with Temperature

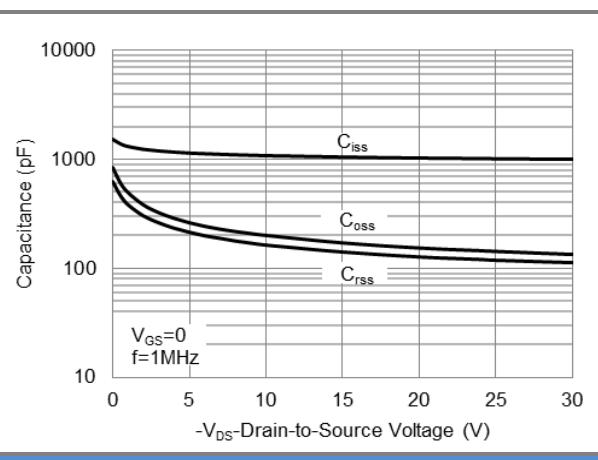


Fig.10 Capacitance vs. Drain-Source Voltage

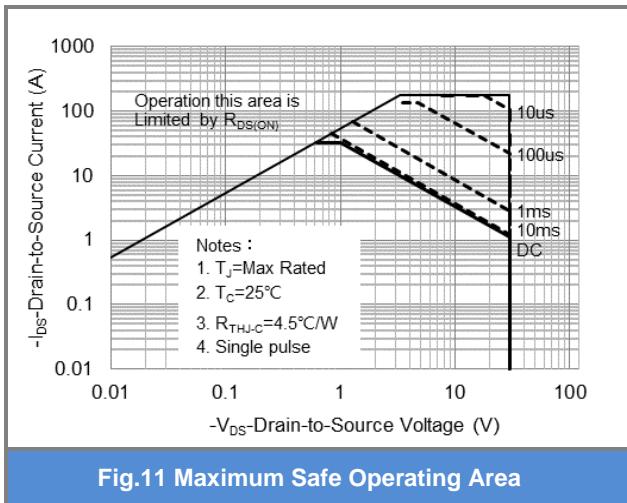


Fig.11 Maximum Safe Operating Area

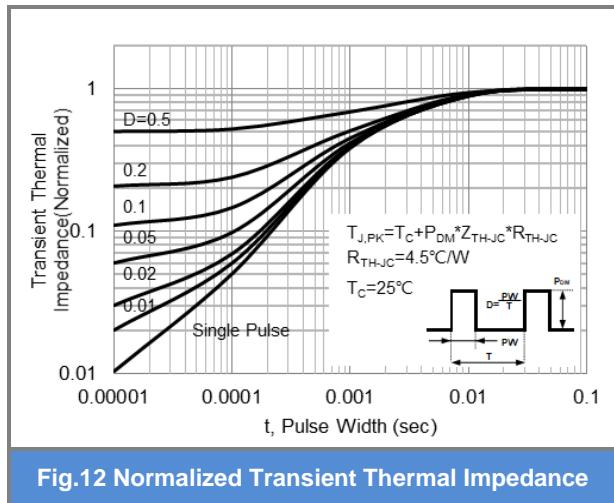


Fig.12 Normalized Transient Thermal Impedance

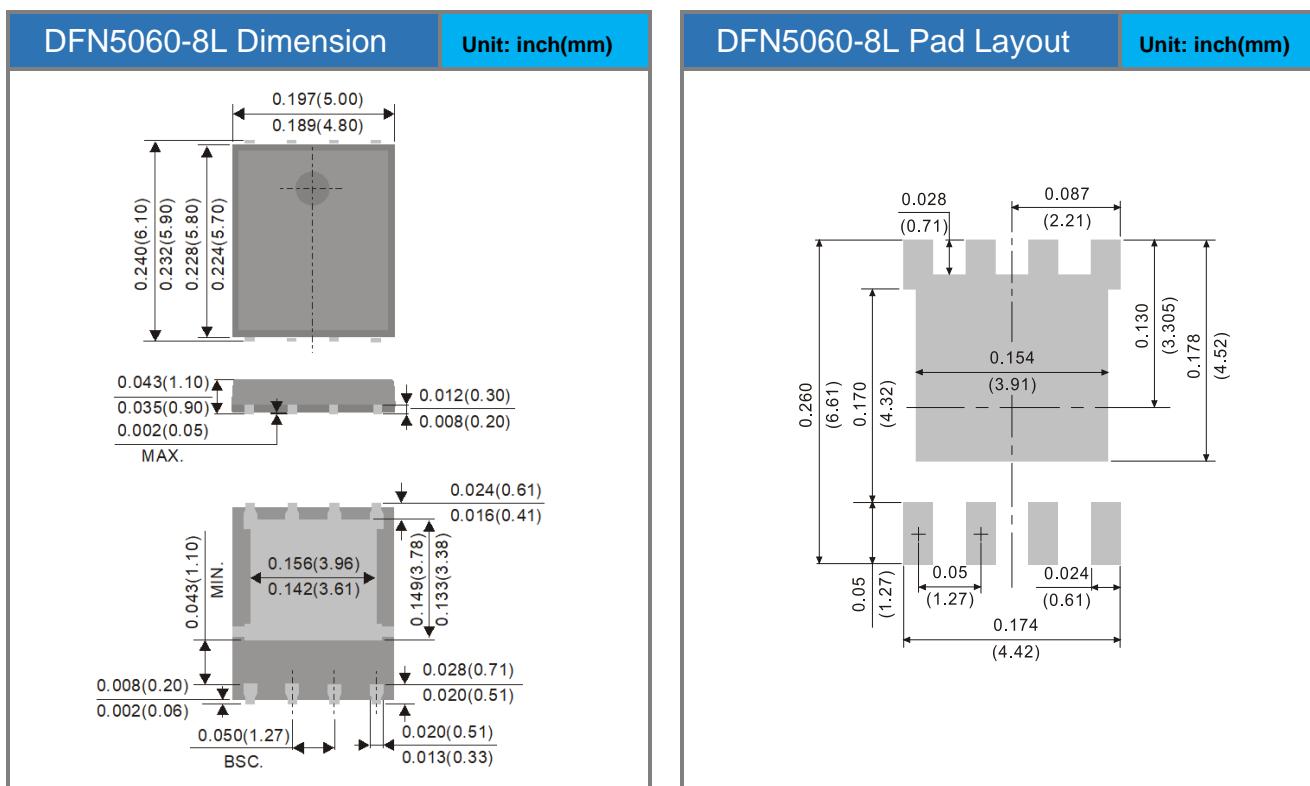


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Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PJQ5439E-AU	DFN5060-8L	3K pcs / 13" reel	Q5439E

Packaging Information & Mounting Pad Layout





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